



# Study on the evolution processes from $TiC_x$ to $TiB_2$ induced by B in Al melt



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## ABSTRACT

The structural evolution from  $TiC_x$  to  $TiB_2$  induced by the B element in the aluminum melt has been investigated and the possible evolution mechanism has been revealed. Based on the FESEM observations, it is found that the evolution takes place in three steps, i.e. the delamination of  $TiC_x$ , in situ crystallization of  $TiB_2$  on the  $TiC_x$  nanolamellas, the orientated attachment and Ostwald ripening during the  $TiB_2$  growing process.

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## 1. Introduction

$TiB_2$  and  $TiC_x$  are important ceramic materials and have received increasing attention because of their excellent physical and mechanical properties, such as high melting point, superior hardness, high modulus, low coefficient of thermal expansion as well as high chemical stability [1]. They are widely used as refractory materials for cutting tools and wear resistant component, especially as reinforcing phases in composites [2,3]. Furthermore, both of them can act as the effective nucleating substrates for  $\alpha$ -Al grain in aluminum alloys during the solidification process, due to their good lattice matching as well as their specific physical and chemical properties [4,5].

However, it was found that  $TiC_x$  was unstable in the aluminum alloy melts and reacted with other elements (Al, Si, B, etc.) during the holding time, which influenced its application in Al–Ti–C grain refiners and metal matrix composites [6,7]. Although Al–Ti–B master alloys containing  $TiB_2$  are the preferred choice for grain refinement of wrought aluminum alloy in industry, the agglomeration of  $TiB_2$  particles is a serious disadvantage for the grain refinement in some cases [8]. It can cause many problems in some cases, such as the porosity, streaking in aluminum foils and internal cracking in extrusion billets. Thus, it is really urgent to take effective ways to control the growth and agglomeration of  $TiB_2$  particles in aluminum alloy melt.

Recently, it was found that the structural instability and evolution of  $TiC_x$  induced by B element in Al melt were effectively used to prepare a

kind of titanium diboride core–shell structure particles, which displayed an effective grain refining efficiency [9,10]. Furthermore, the size and morphologies of the  $TiB_2$  particles can be effectively controlled during the transformation. However, the transformation mechanism has not yet been fully understood. Herein, a study on the evolution processes from  $TiC_x$  to  $TiB_2$  has been taken. We report for the first time the observation of the exfoliation of  $TiC_x$  crystals induced by B in Al melt, and the in situ crystallization mechanism of  $TiB_2$  on  $TiC_x$  nanosheets has been raised based on the FESEM observations.

## 2. Experimental procedure

The materials used are 99.7 wt.% commercial pure aluminum, 99.85 wt.% graphite powder with size about 10  $\mu$ m, 99.5 wt.% pure titanium and Al–3B alloy. Firstly, Al–Ti–C was prepared by the melt reaction method and weight ratio of Ti: C was fixed at 4:1 with the normal composition of Al–2.2Ti–0.55C. The graphite, Ti and pure Al powders were mixed and ball milled for 9 h, and then cold-pressed into pellets. Subsequently, the pellets were added into the Al melt at 1200 °C to prepare Al–Ti–C. Then, the Al–Ti–C was re-melted to above 1100 °C and 0.75 wt.% B in form of Al–3B was added into the melt to induce the transformation of  $TiC_x$ . Then the alloy was poured after holding for 5 s, 30 s, 60 s, and 2 min, respectively.

In order to obtain  $TiC_x$  and  $TiB_2$ , the bulk samples were dissolved in a 10 vol.% HCl–distilled water solution to remove Al matrix. The solutions with remaining particles were centrifuged by a centrifugal extractor. After that, the collected sedimented particles were rinsed with distilled water and ethanol for several times and then desiccated. The extracted particles were characterized by field emission scanning electron microscope (FESEM, SU-70, Japan and FEI Quanta 250, US) equipped with an

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energy-dispersive X-ray spectroscopy (EDS) and high resolution transmission electron microscopy (HRTEM, FEI Tecnai 20, US).

### 3. Results and discussion

Fig. 1a shows the FESEM image of TiC<sub>x</sub> particles extracted from the above Al–Ti–C system. It can be seen that most of the TiC<sub>x</sub> particles display the typical truncated octahedron morphology enclosed by eight smooth {111} and six {100} facets due to the non-equilibrium growth condition in the Al melt [11]. However, after the addition of B element into the Al melt for a short time, the six {100} facets on the TiC<sub>x</sub> truncated octahedron turn to be rather rough as shown by the arrows in Fig. 1b and seem to be selectively etched as shown by the magnified picture. Meanwhile, the B element directly caused the etching of the eight edges corresponding to {110} planes and cracks were formed as shown by the arrows in Fig. 1c–d. It is known that the surface energy ( $\gamma$ ) of the {110} and {100} facets is much higher than that of {111} [12,13]. In general, the surface with higher surface energy always has higher absorption energy and is more unstable during the transformation process in the melt. After Al–B alloy added in the melt, B atoms are prone to be absorbed on the {110} and {100} planes preferentially and then dope into the inner lattice structure of TiC<sub>x</sub> due to lots of C vacancies. Meanwhile, lots of Ti–C bonds were broken and then C and Ti atoms diffused outward into the melt resulting in the rough surface and cracked edges. Thus, the transformation of TiC<sub>x</sub> introduced by the B in the Al melts started from the selective etching on {100} and {110} planes at the initial stage.

With the prolonged holding time, {100} facets of TiC<sub>x</sub> octahedron became more rough and then holes were formed as shown by the arrows in the Fig. 2a–b, and the cracks formed on the {110} edges were also broader. Furthermore, visible delamination on {111} surfaces can be seen in Fig. 2b–c and then lamellas with thickness about 50–100 nm were formed, which could also be defined as two-dimensional

nanocrystals [14]. It indicates that the nanolamellas are separated and will exfoliate from the {111} surface layer by layer as seen in Fig. 2c–d. The delamination phenomena are supposed to be induced by the doping of B into the lattice structure of TiC<sub>x</sub> and is confirmed by the EDS analysis as shown in Fig. 2e–f, in which the peaks of B element appear. It is supposed that the Ti–C bonding has been broken and Ti–B bonding has formed instead. So, the formation of cracks is considered to be a result from the broken Ti–C bonding and the outward diffusion of C atoms.

Fig. 3 displays the morphologies of the particles in the Al–Ti–C–B system after adding B for 60 s and it can be seen that lots of regular hexagonal prisms with submicron size have formed on the original nanolamellas of TiC<sub>x</sub> as shown in Fig. 3a–c. Figs. 3e–f show the TEM images of the hexagonal platelets and the corresponding selected-area electron diffraction (SAED), which confirm that the regular hexagonal prism is the formed TiB<sub>2</sub>.

It is suggested that TiC<sub>x</sub> and TiB<sub>2</sub> could establish coherency between their most close-packed lattice planes, which are (111) of TiC<sub>x</sub> and (0001) of TiB<sub>2</sub> [15]. The arrangement of Ti atoms in both of them is almost the same, as shown in Fig. 4. The degree of disregistry between the substrate phase and the crystalline phase can be measured by the Turnbull–Vonnegut equation:

$$\delta = \frac{|a_c - a_s|}{a_c} \times 100\% \tag{1}$$

where  $a_s$  and  $a_c$  are the interatomic distances of the substrate plane and crystalline plane, respectively. The lattice mismatch of TiC<sub>x</sub> (111) plane and TiB<sub>2</sub> (0001) plane is:

$$\delta = \frac{|a_{\text{TiB}_2} - a_{\text{TiC}}|}{a_{\text{TiB}_2}} \times 100\% = \frac{|3.028 - 3.060|}{3.028} \times 100\% = 1.057\%.$$

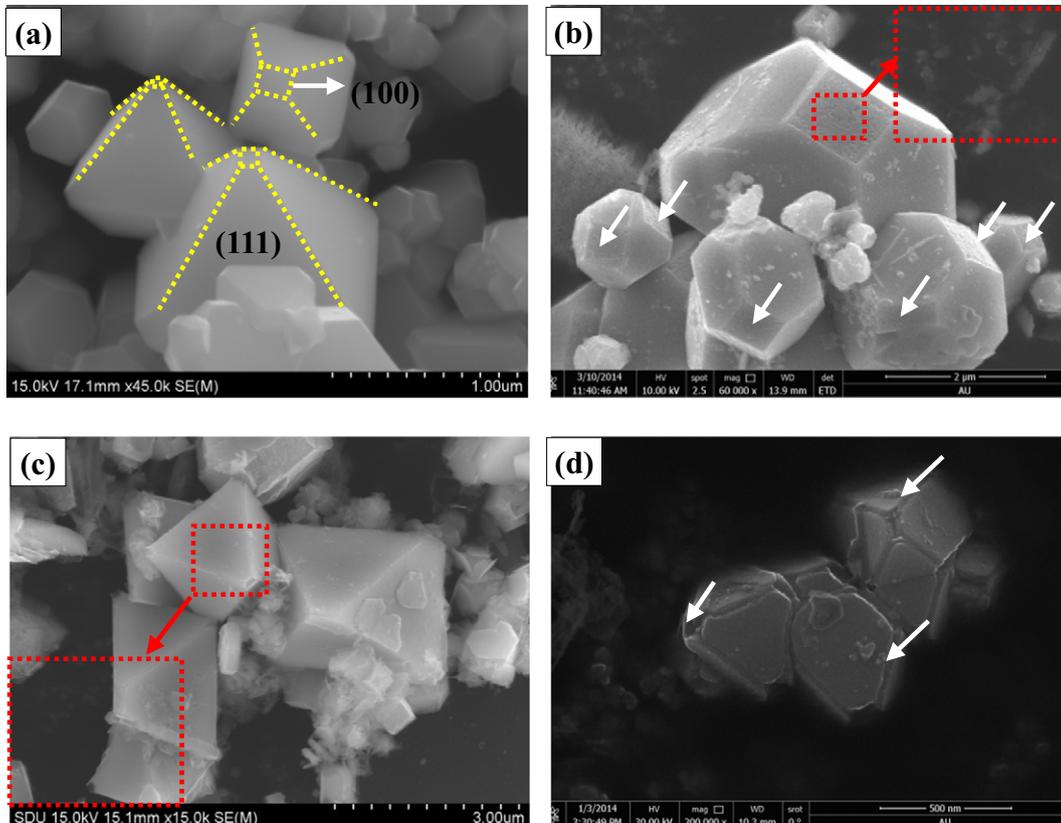


Fig. 1. Typical morphologies of TiC<sub>x</sub> extracted from: (a) Al–Ti–C system; and (b–d) after B addition holding for 5 s.

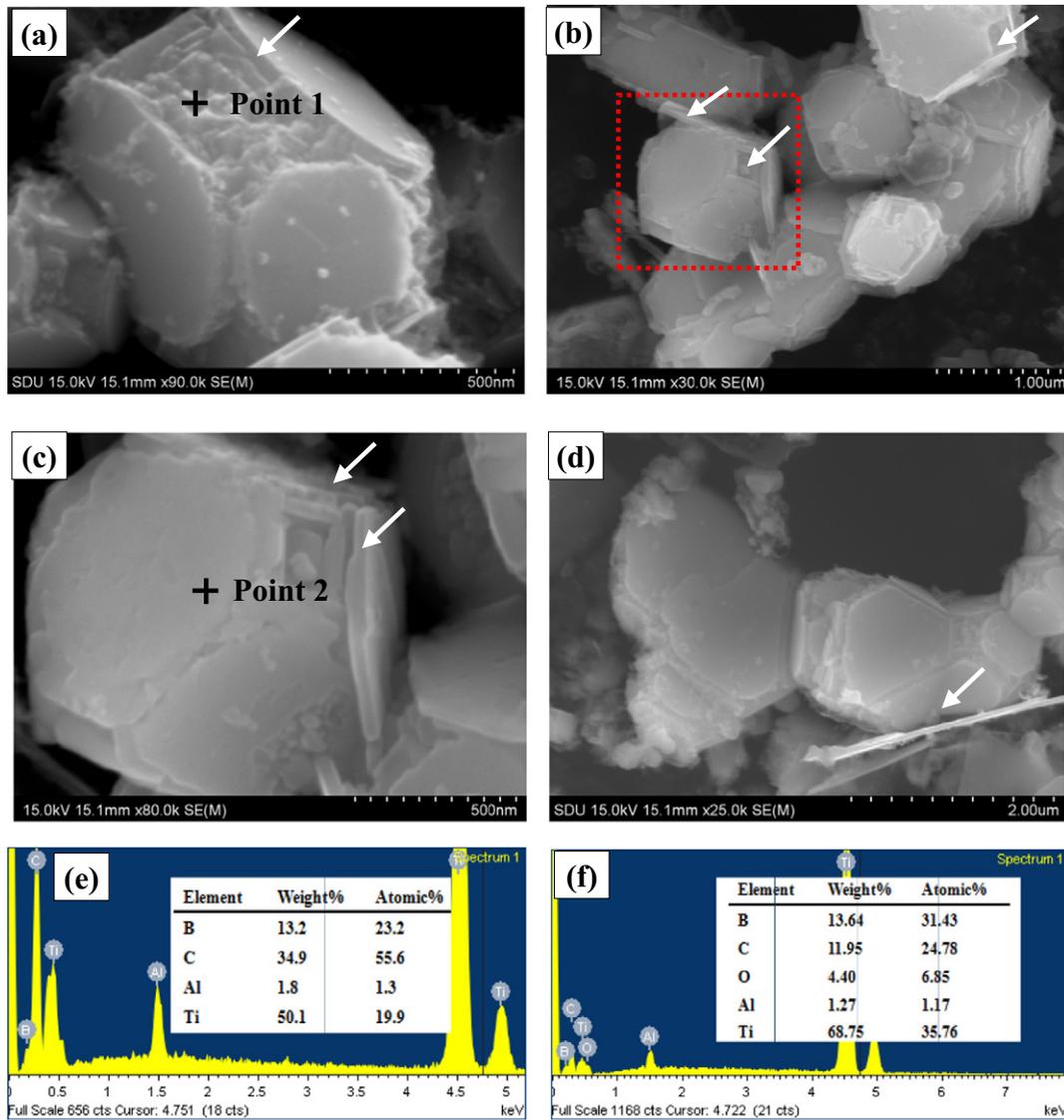


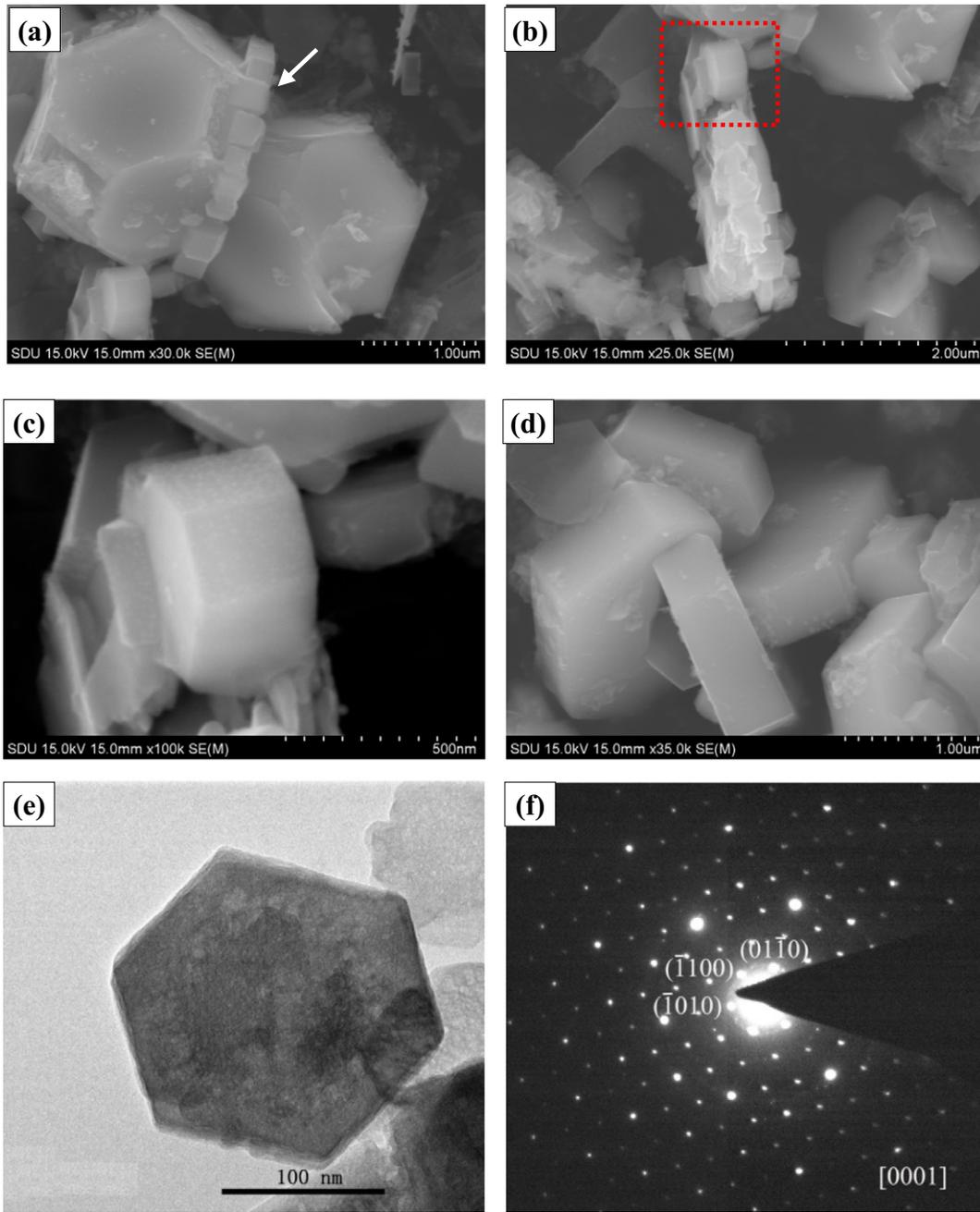
Fig. 2. Morphologies of  $TiC_x$  particles extracted from the Al–Ti–C–B system after B addition holding for 30 s (a–d) and the corresponding EDS analysis of Point 1 and Point 2 (e–f).

The result indicates that  $TiC_x$  (111) and  $TiB_2$  (0001) are coherent interfaces. Thus, it is reasonable to believe that the surface of nanolamellas corresponding to {111} planes of  $TiC_x$  crystals can act as the nucleating substrates of  $TiB_2$  crystals. It can be considered that the selective etching of {110} and {100} planes provides channels for atomic diffusion of B atoms and promotes the nucleation and growth of  $TiB_2$ . Furthermore, a piece of lamella may supply more than one nucleating site for  $TiB_2$ , and it can be seen that many small  $TiB_2$  hexagonal prisms aggregate on the same surface as shown in Fig. 3a–b. The doping of more B atoms induce the broken of more Ti–C bonding and the gradual dissolution of  $TiC_x$  lamella, and then promotes the formation of Ti–B bonding and growth of  $TiB_2$ . Meanwhile, the  $TiB_2$  hexagonal prisms nucleating on the same substrates share a common crystallographic orientation, and the regular oriented attachment is an important growth mechanism of these aggregates of  $TiB_2$  to reduce the total interfacial energy [16]. Besides, the adjacent  $TiB_2$  hexagonal prisms nucleating on different planes may connect with each other by certain planes as shown by Fig. 3d, which is referred as imperfect oriented attachment.

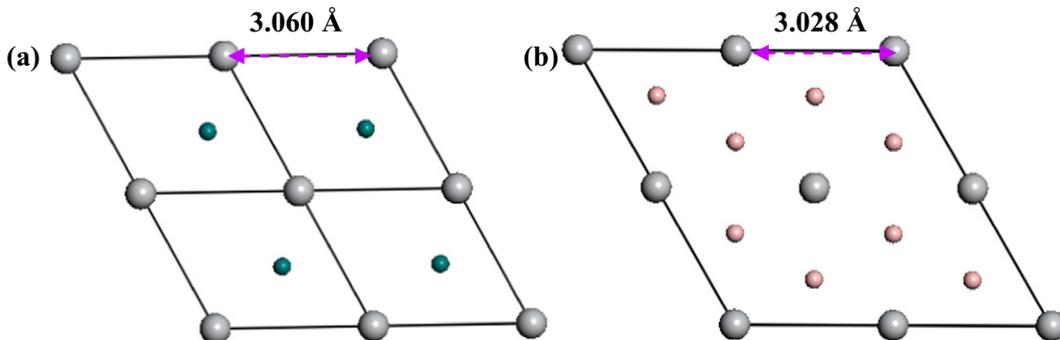
Fig. 5 shows the typical morphologies of particles extracted from the Al–Ti–C–B alloy after adding B for 2 min. Most of polyhedral  $TiC_x$  particles were transferred into hexagonal  $TiB_2$ , which indicated that the transformation process finished completely. Compared with Fig. 4, the width of most  $TiB_2$  increased obviously and the edges became much

smoother. It is considered that the growth of  $TiB_2$  mainly occurs in this stage. Besides, some tiny particles can also be seen as shown in Fig. 5a. Therefore, it is supposed that the Ostwald ripening mechanism dominates the growth process of  $TiB_2$ , involving preferential dissolution of smaller  $TiB_2$  particles and recrystallization and growth of larger  $TiB_2$  particles [17,18]. Since the smaller particles have a lower thermodynamic stability and a higher surface to volume ratio [18], the ripening process leads to the slow disappearance of the small particles and the continuous growth of large particles to minimize the surface energy. The edges and corners of the left small  $TiB_2$  hexagonal prisms become much smoother as shown in Fig. 5c, which also confirms the Ostwald ripening mechanism. It can be also noted that the larger  $TiB_2$  particles are not regular hexagonal prisms, which is caused by the non-equilibrium state of the Al melt. According to the EDS result, trace amount of C is always detected in the  $TiB_2$ , which has been revealed in our previous study [9]. It is considered that the doping of trace C can introduce many lattice defects and distortion in the crystal structure of  $TiB_2$  and may be another reason for the irregular hexagonal morphology.

It was found that the reaction between TiC and B to form  $TiB_2$  was thermally favorable [19]. According to chemical thermal data provided by Liang and Che [20], the Gibbs' free energy for the following reaction at 1400 K is calculated about  $-412.6$  kJ/mol, indicating the instability of



**Fig. 3.** Morphologies of extracted  $TiC_x$  and  $TiB_2$  particles at the end of the transformation after holding for 60 s (a–d) and the corresponding TEM image and SAED pattern of hexagonal  $TiB_2$  (e–f).



**Fig. 4.** The atom arrangement on: (a)  $TiC_x$  (111) and (b)  $TiB_2$  (0001) planes. The gray balls denote Ti atoms, blue ones represent C atoms and the pink ones are B.

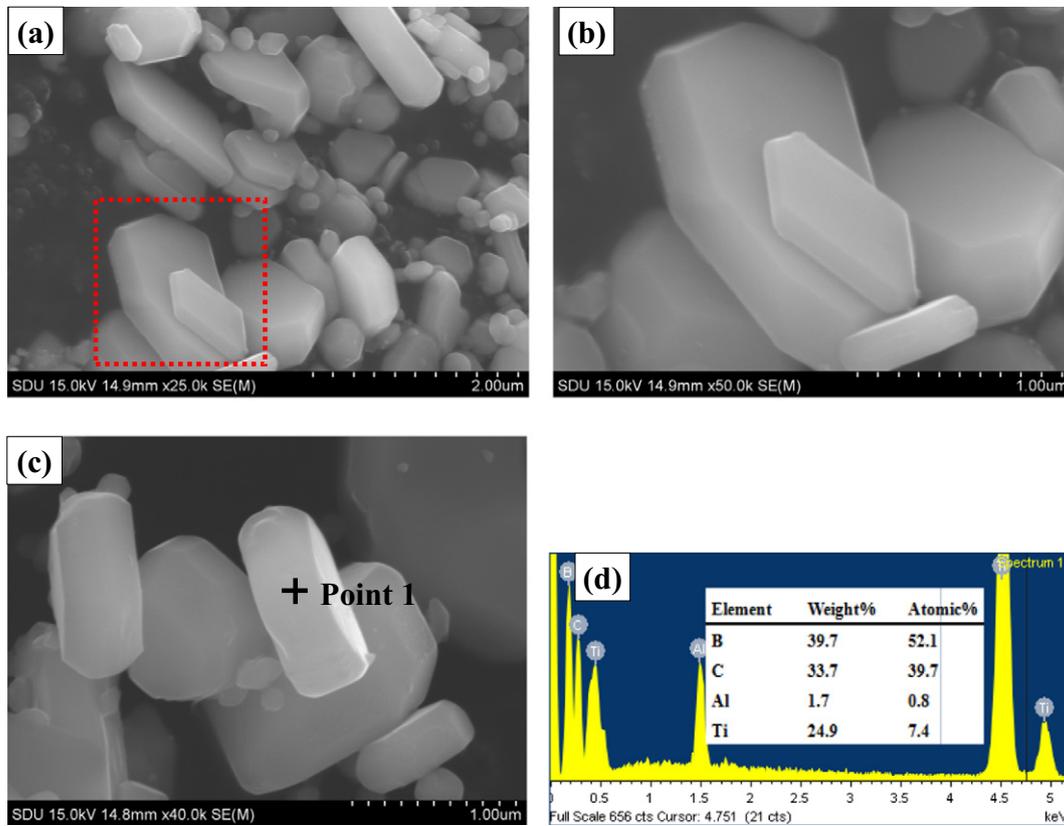


Fig. 5. FESEM images of  $\text{TiB}_2$  particles extracted from Al–Ti–C–B system after adding B for 2 min: (a–c) typical morphologies of  $\text{TiB}_2$ ; and (d) EDS analysis of Point 1.

$\text{TiC}$  compared to  $\text{TiB}_2$  in the Al melt. Besides, the C atoms diffused from the  $\text{TiC}_x$  combine with Al atoms surrounded to form the  $\text{Al}_4\text{C}_3$  solid phase and then the reaction proceeds continually. Thus, the Al melt also promotes the reaction between  $\text{TiC}$  and B kinetically.



Base on the above analysis and observations, the evolution processes from  $\text{TiC}_x$  to  $\text{TiB}_2$  can be divided into three steps and are tentatively summarized as follows. Firstly, the evolution starts from cracking of  $\{110\}$  edges and selective etching of  $\{100\}$  surfaces induced by the excess doping of B in the lattice crystal structure of  $\text{TiC}_x$ , the C vacancy defect in which also do favor for this process. Due to the strong covalent bond of Ti–B, the original of Ti–C bond is broken leading to the outward diffusion of C atoms. Because  $\{111\}$  is a kind of polar face with only Ti or C atoms on one layer, the broken Ti–C bond will lead

to the weak bonding between  $\{111\}$  planes and to further delamination. Then, lots of nanolamellas with thickness smaller than 100 nm exfoliated from the  $\{111\}$  surfaces layer by layer.

We note that this is the first time that we reveal the delamination phenomena of  $\text{TiC}_x$  induced by the B element in the Al melt. Besides, Barsoum et al. reported a kind of new exciting 2D transition metal carbides  $\text{Ti}_2\text{C}$ ,  $\text{Ti}_3\text{C}_2$  produced by the exfoliation of  $\text{Ti}_2\text{AlC}$ ,  $\text{Ti}_3\text{AlC}_2$  and utilizing the selective etching of Al layers from the MAX phases in the HF treatment [14,21]. Inspired by their research results, it is supposed that 2D  $\text{TiC}_x$  could be produced in our system if the doping process of B was effectively controlled by the extremely low B concentration in order to impede the nucleation process of  $\text{TiB}_2$ , which will be studied in our future work.

Secondly, in the in situ crystallization of  $\text{TiB}_2$  hexagonal prism from  $\text{TiC}_x$ , the exfoliated  $\text{TiC}_x$  nanosheet serves as the nucleating substrates of  $\text{TiB}_2$  due to the crystal lattice match between  $\text{TiC}_x$   $\{111\}$  faces and

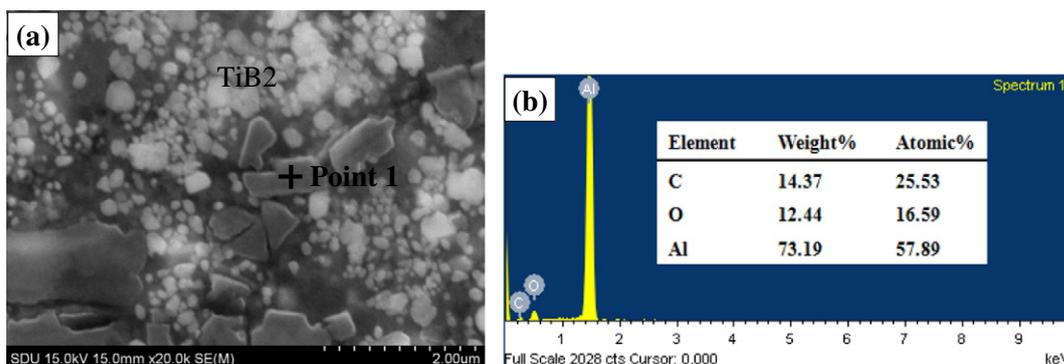


Fig. 6. Microstructures of the prepared Al–Ti–C–B alloys after adding B for 2 min (a) and the EDS analysis of Point 1 (b).

{0001} planes of  $\text{TiB}_2$ . The growth of  $\text{TiB}_2$  nucleus is facilitated by the dissolution of  $\text{TiC}_x$  nanosheet and the deposition of B atoms. Moreover, a piece of lamella can supply many nucleating sites for  $\text{TiB}_2$  hexagonal prisms, which share a common crystallographic orientation, thus regular oriented attachment becomes an important growth mechanism of these  $\text{TiB}_2$  and then the hexagonal  $\text{TiB}_2$  plates form. It is known that the growth of  $\text{TiB}_2$  is limited by the exfoliation of  $\text{TiC}_x$  and the dissolution rate of the lamella, and vice versa. Thus, the growth rate of  $\text{TiB}_2$  is relatively low compared with that formed by the direct reaction of B and Ti atoms in the Al melt at the similar melt reaction temperature [8,9].

Besides, Fig. 6a shows the microstructure of the prepared Al–Ti–C–B alloy after adding B for 2 min and it can be seen that the sub-micro white particles are  $\text{TiB}_2$  distributed in the Al matrix. While the gray phase is  $\text{Al}_4\text{C}_3$  which can be confirmed by the EDS result in Fig. 6b and indicates that the C atoms outward diffused from  $\text{TiC}_x$  combine with Al atoms surrounded. Lastly, the  $\text{TiB}_2$  crystal continues to grow if the melt holding time is prolonged. Ostwald ripening mechanism dominates by the preferential dissolution of smaller  $\text{TiB}_2$  particles and recrystallization and growth of larger  $\text{TiB}_2$  particles.

#### 4. Conclusions

In summary, the kinetic evolution processes from  $\text{TiC}_x$  to  $\text{TiB}_2$  have been investigated. FESEM observations allow us to draw the conclusion that the evolution takes place in three steps, i.e. the gradual delamination of  $\text{TiC}_x$ , in situ crystallization of  $\text{TiB}_2$  on the exfoliated  $\text{TiC}_x$  nanolamellas, the orientated attachment growth and Ostwald ripening during the  $\text{TiB}_2$  growing process. The new findings here should let one better understand the similar evolution of transition metal carbides induced by the impurity element in the metal melt.

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